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FDD6N20TM N-Channel UniFETTM MOSFET 200 V, 4.5 A, 800 mΩ

Features

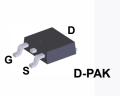
- + $R_{DS(on)}$ = 600 m Ω (Typ.) @ V_{GS} = 10 V, I_D = 2.3 A
- Low Gate Charge (Typ. 4.7 nC)
- Low C_{rss} (Typ. 6.3 pF)
- 100% Avalanche Tested
- RoHS Compliant

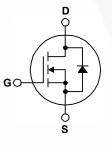
Applications

- LCD/LED/PDP TV
- Consumer Appliances
- Lighting
- Uninterruptible Power Supply

Description

UniFETTM MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.





MOSFET Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter			FDD6N20TM	Unit	
V _{DSS}	Drain to Source Voltage		200	V		
V _{GSS}	Gate to Source Voltage			±30	V	
	Drain Current	- Continuous (T _C = 25 ^o C)		4.5		
I _D		- Continuous (T _C = 100 ^o C)		2.7	A	
I _{DM}	Drain Current	- Pulsed	(Note 1)	18	А	
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		(Note 2)	60	mJ	
I _{AR}	Avalanche Current		(Note 1)	4.5	А	
E _{AR}	Repetitive Avalanche Energy		(Note 1)	4.0	mJ	
dv/dt	Peak Diode Recovery dv/dt (Note 3)		(Note 3)	4.5	V/ns	
P _D	Deven Dississeties	$(T_{\rm C} = 25^{\rm o}{\rm C})$		40	W	
	Power Dissipation	- Derate Above 25°C		0.32	W/ ^o C	
T _J , T _{STG}	Operating and Storage Temperature Range			-55 to +150	°C	
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		conds	300	°C	

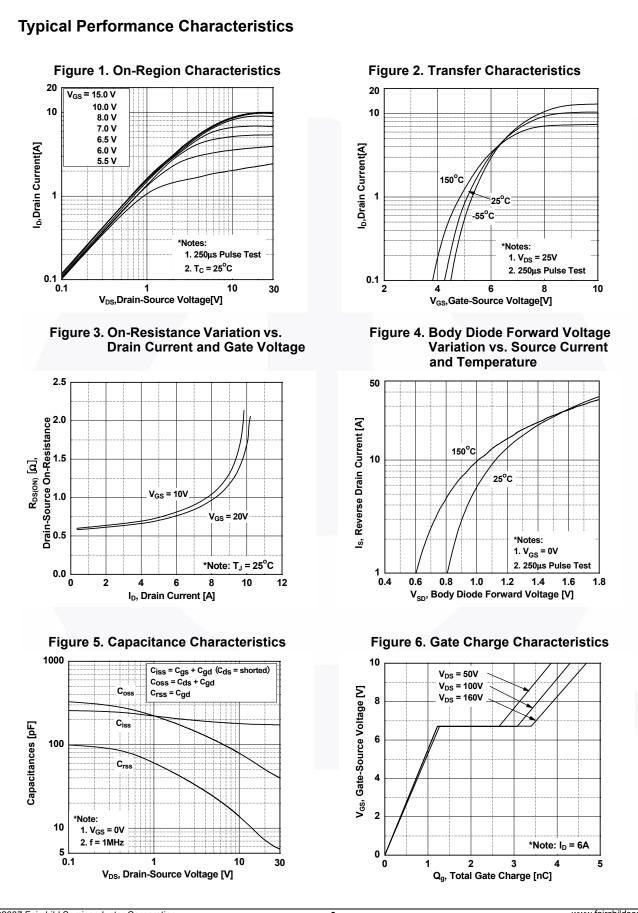
Thermal Characteristics

Symbol	Parameter	FDD6N20TM	Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	3.1	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient, Max.	110	C/W

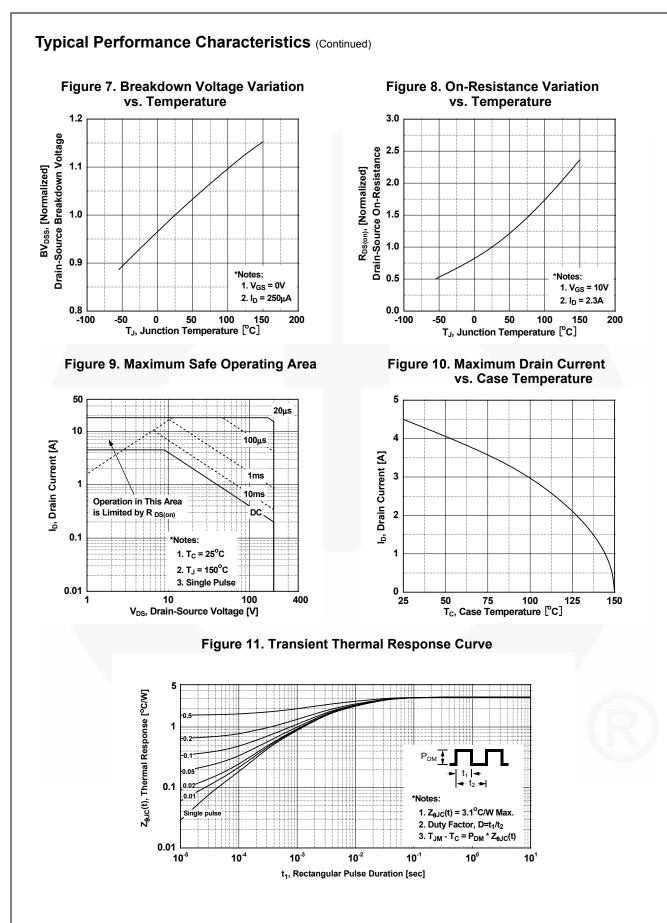
November 2013

Part NumberTop MarkFFDD6N20TMFDD6N20		Package	Packing Method	Reel Size	e Ta	ape Width	Quantity		
		DPAK			-		2500 units		
Electrica	l Chara	cteristics T _C = 25°C	unless othe	erwise noted.					
Symbol		Parameter		Test Conditions	S	Min.	Тур.	Max.	Unit
Off Charac	teristics				·				
BV _{DSS}	Drain to S	Source Breakdown Voltage	lo =	= 250 μA, V _{GS} = 0 V, T	₁ = 25 ^o C	200	_	-	V
ΔBV_{DSS}	Breakdov	vn Voltage Temperature		250 μA, Referenced t		-	0.28	-	V/ºC
$/\Delta T_J$	Coefficier	Coefficient						4	
I _{DSS}	Zero Gate Voltage Drain Current			$V_{DS} = 200 V, V_{GS} = 0 V$ $V_{DS} = 160 V, T_{C} = 125^{\circ}C$		-	-	1	μA
1	Cata ta B	ody Leakage Current	-	$r_{S} = \pm 30 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$		-	-	10 ±100	nA
I _{GSS}	Gale IO D		V GS	$_{\rm S} = \pm 30$ V, V _{DS} = 0 V		-	-	±100	ПА
On Charac	teristics								
V _{GS(th)}	Gate Thre	eshold Voltage	V _G	_S = V _{DS} , I _D = 250 μA		3.0	-	5.0	V
R _{DS(on)}	Static Dra	ain to Source On Resistance	V _G	_S = 10 V, I _D = 2.3 A		-	0.6	0.8	Ω
9 _{FS}	Forward ⁻	Transconductance	V _{DS}	_S = 40 V, I _D = 2.3 A		-	2.9	-	S
Dynamic C	haracter	istics							
C _{iss}	Input Cap					-	170	230	pF
C _{oss}		apacitance	V _{DS} = 25 V, V _{GS} = 0 V,		-	-	45	60	pF
C _{rss}		Transfer Capacitance	f =	f = 1 MHz		-	6.3	9.5	pF
Q _{g(tot)}		e Charge at 10V	V	$V_{DS} = 160 \text{ V}, \text{ I}_{D} = 6 \text{ A},$ $V_{GS} = 10 \text{ V}$ (Note 4)		-	4.7	6.1	nC
Q _{gs}		ource Gate Charge	VDS VGS			-	1.2	-	nC
Q _{gd}	Gate to D	rain "Miller" Charge				-	2.2	-	nC
Switching	Characte	prietics							
t _{d(on)}		Delay Time				-	8.3	26.7	ns
t _r		Rise Time	VDL	V_{DD} = 100 V, I _D = 6 A, V _{GS} = 10 V, R _G = 25 Ω (Note 4)		-	5.6	21.2	ns
t _{d(off)}		Delay Time					15	40	ns
t _f	Turn-Off F	,					12.8	35.5	ns
					()		_		
Drain-Sou	1	e Characteristics					ГГ		r -
I _S	Maximum Continuous Drain to Source Di					-	-	4.5	A
ISM		Maximum Pulsed Drain to Source Diode F				-	-	18	Α
V _{SD}		ource Diode Forward Voltag		00 00		-	-	1.4	V
t _{rr}		Recovery Time		$_{S} = 0 V, I_{SD} = 6 A,$	-	-	120		ns
Q _{rr}	Reverse F	everse Recovery Charge dI _F /dt = 100 A/μs			-	0.4	-	μC	

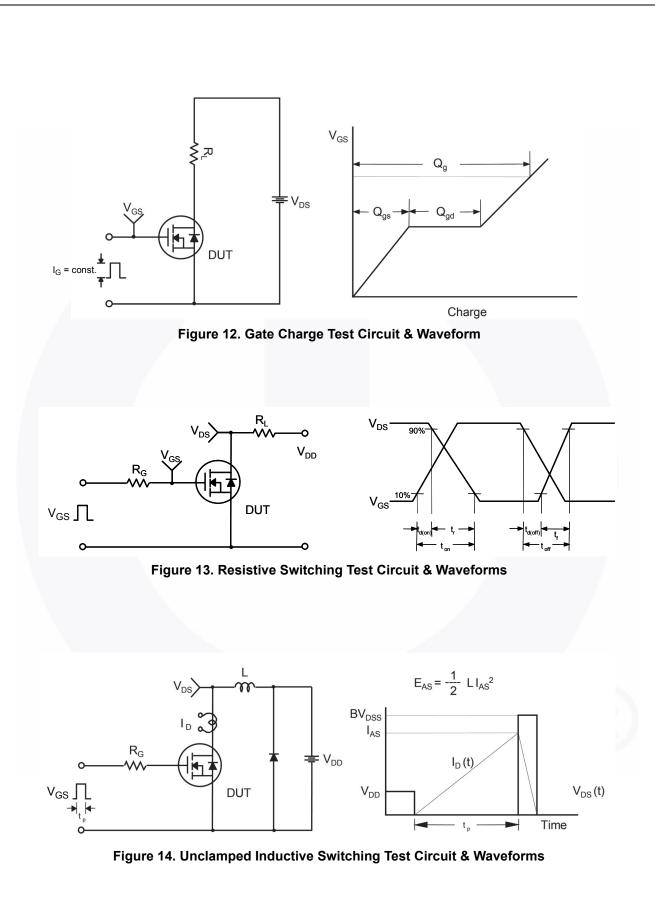
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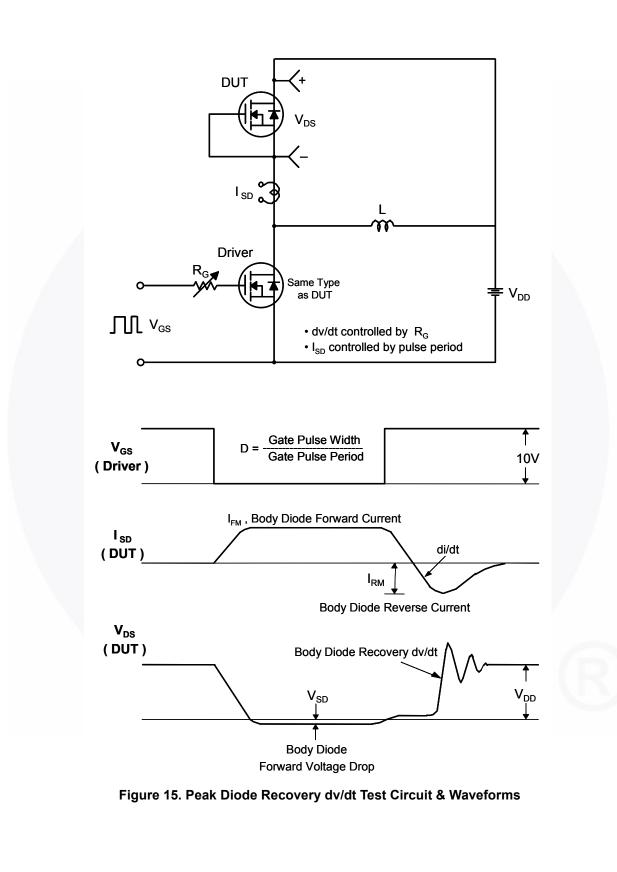


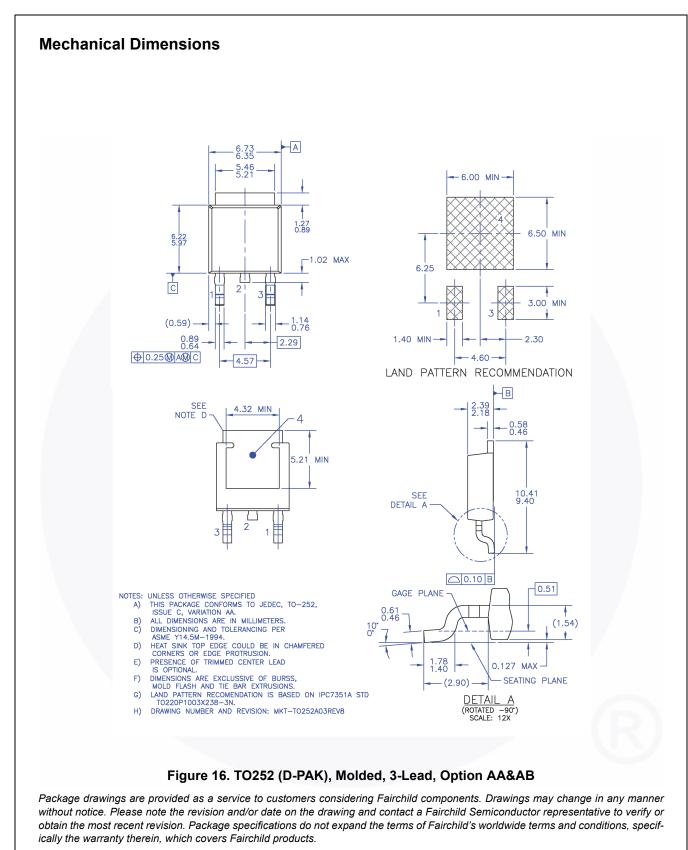
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